

SOT-23 Plastic-Encapsulate MOSFETs

N-Channel Enhancement Mode Field Effect Transistor

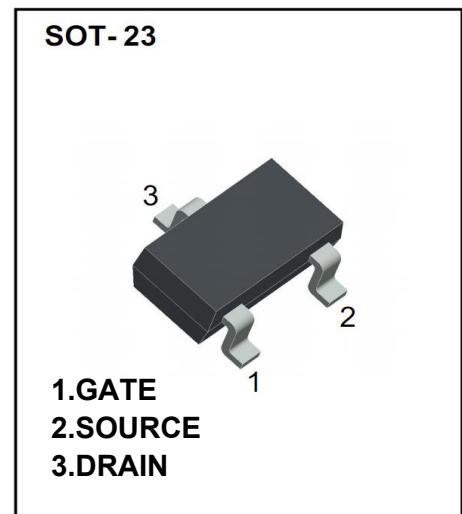
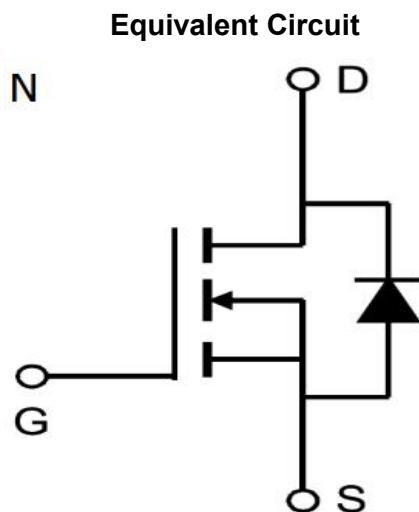
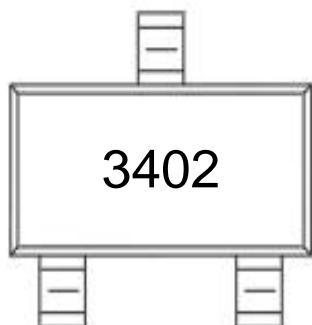
FEATURES

- Lead free product is acquired
- Surface mount package

APPLICATION

- Load Switch and in PWM applications

MARKING



Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	4	A
Pulsed Drain Current (note 1)	I_{DM}	15	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient (note 2)	$R_{\theta JA}$	357	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55~+150	°C

Electrical characteristics ($T_a=25^\circ\text{C}$ unless otherwise noted)

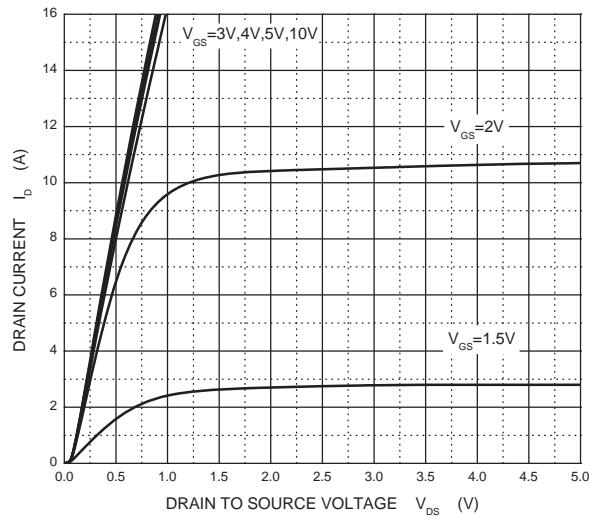
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_{\text{D}} = 250\mu\text{A}$	30			V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}} = 24\text{V}, V_{\text{GS}} = 0\text{V}$			1	μA
Gate-body leakage current	I_{GSS}	$V_{\text{GS}} = \pm 12\text{V}, V_{\text{DS}} = 0\text{V}$			100	μA
Gate threshold voltage (note 3)	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = 250\mu\text{A}$	0.6	1	1.4	V
Drain-source on-resistance (note 3)	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = 10\text{V}, I_{\text{D}} = 4\text{A}$		45	55	$\text{m}\Omega$
		$V_{\text{GS}} = 4.5\text{V}, I_{\text{D}} = 3\text{A}$		55	70	$\text{m}\Omega$
		$V_{\text{GS}} = 2.5\text{V}, I_{\text{D}} = 2\text{A}$		83	110	$\text{m}\Omega$
Forward transconductance (note 3)	g_{FS}	$V_{\text{DS}} = 15\text{V}, I_{\text{D}} = 4\text{A}$		8		S
Diode forward voltage (note 3)	V_{SD}	$I_{\text{S}} = 1\text{A}, V_{\text{GS}} = 0\text{V}$		0.8	1	V
DYNAMIC CHARACTERISTICS (note 4)						
Input capacitance	C_{iss}	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		390		pF
Output capacitance	C_{oss}			54.5		pF
Reverse transfer capacitance	C_{rss}			41		Pf
Gate resistance	R_g	$V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		3		Ω
SWITCHING CHARACTERISTICS (note 4)						
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{GS}} = 10\text{V}, V_{\text{DS}} = 15\text{V}, R_L = 3.75\Omega, R_{\text{GEN}} = 6\Omega$		3.3		ns
Turn-on rise time	t_r			1		ns
Turn-off delay time	$t_{\text{d}(\text{off})}$			21.7		ns
Turn-off fall time	t_f			2.1		ns
Total gate charge	Q_g	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = 4.5\text{V}, I_{\text{D}} = 4\text{A}$		4.34		nC
Gate-source Charge	Q_{gs}			0.6		nC
Gate-drain Charge	Q_{gd}			1.38		nC
Body diode reverse recovery time	t_r	$I_F = 4\text{A}, dI/dt = 100\text{A}/\mu\text{s}$		1.2		ns
Body diode reverse recovery charge	Q_{rr}			6.3		nC

Notes :

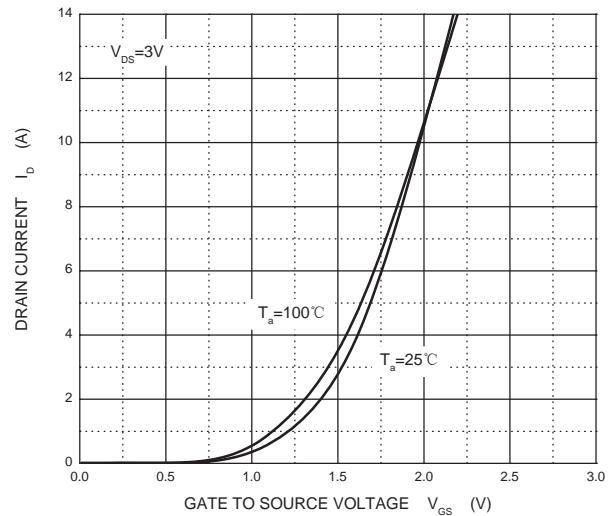
1. Repetitive rating : Pulse width limited by junction temperature.
2. Surface mounted on FR4 board , $t \leq 10\text{s}$.
3. Pulse Test : Pulse Width $\leq 80\mu\text{s}$, Duty Cycle $\leq 0.5\%$.
4. Guaranteed by design, not subject to producting.

Typical Characteristics

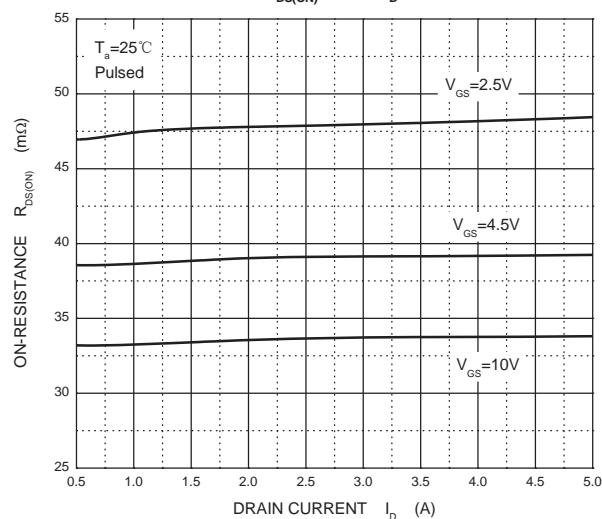
Output Characteristics



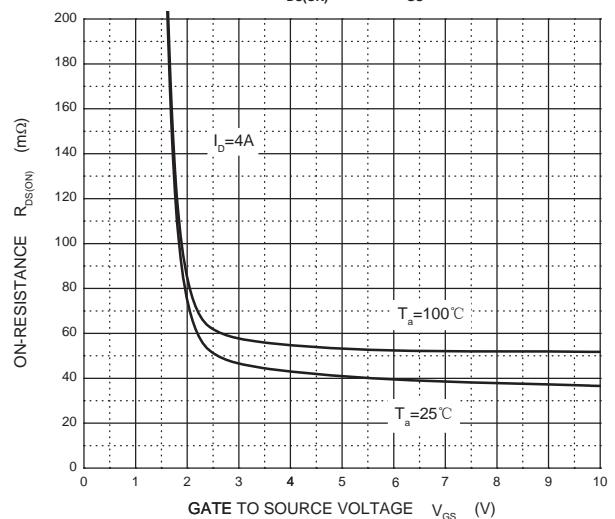
Transfer Characteristics



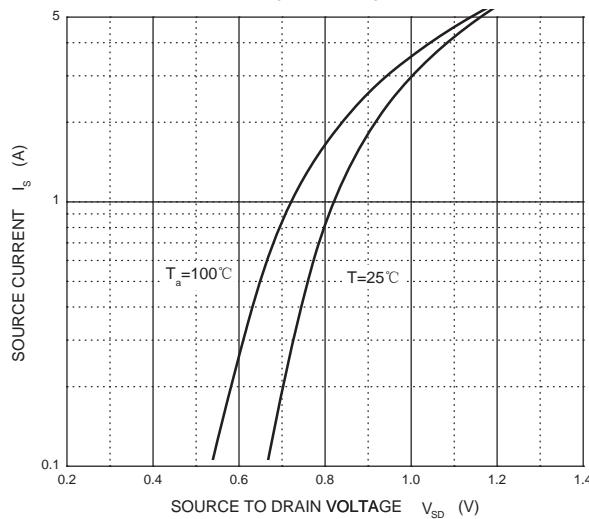
$R_{DS(ON)}$ — I_D



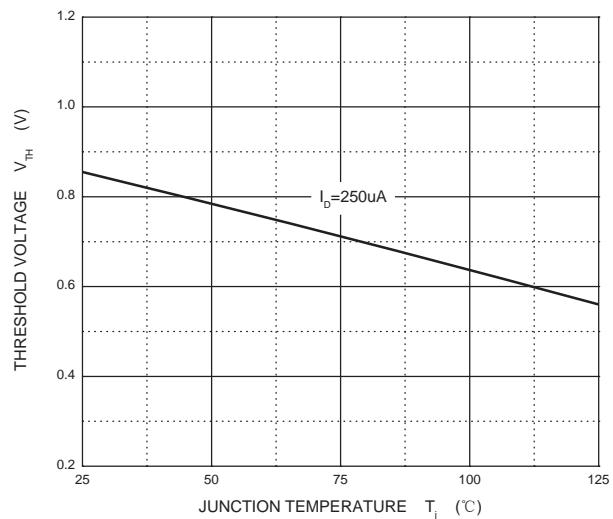
$R_{DS(ON)}$ — V_{GS}



I_S — V_{SD}



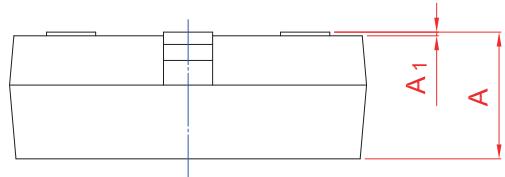
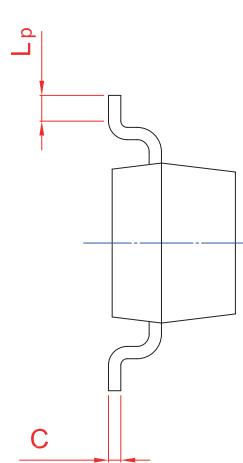
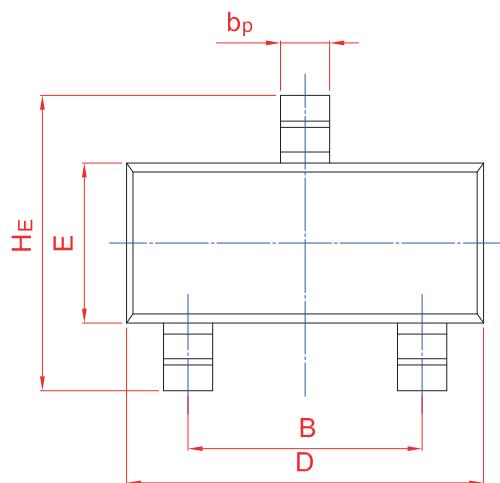
Threshold Voltage



PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b_p	C	D	E	H_E	A_1	L_p
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20

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